

Code No.: R22EC301ES

R22

H.T.No.

8

R

**CMR ENGINEERING COLLEGE: : HYDERABAD**

**UGC AUTONOMOUS**

**II-B.TECH-I-Semester End Examinations (Supply) - June- 2025**

**ANALOG & DIGITAL ELECTRONICS**

**(Common for IT, CSM)**

**[Time: 3 Hours]**

**[Max. Marks: 60]**

**Note:** This question paper contains two parts A and B.

Part A is compulsory which carries 10 marks. Answer all questions in Part A.

Part B consists of 5 Units. Answer any one full question from each unit. Each question carries 10 marks and may have a, b, c as sub questions.

**PART-A**

**(10 Marks)**

1. a) What is the function of a diode as a rectifier? [1M]
- b) Define diode switching times. [1M]
- c) Name the three configurations of a transistor used as an amplifier. [1M]
- d) Define the operating point of a transistor. [1M]
- e) Classify the difference between CS and CD amplifiers? [1M]
- f) State one of De Morgan's Laws. [1M]
- g) What is canonical form? [1M]
- h) What are logic gates & mention all logic gates? [1M]
- i) Difference between a latch and a flip-flop. [1M]
- j) List the applications of a shift register? [1M]

**PART-B**

**(50 Marks)**

2. Demonstrate the V-I characteristics of a diode. Discuss how the characteristics change with temperature variations and the implications of these changes in practical applications. [10M]

**OR**

3. Choose the operation of a diode in clipping and clamping circuits. Provide detailed diagrams, mathematical analysis. [10M]

4. Compare Common Base (CB), Common Emitter (CE), and Common Collector (CC) configurations. [10M]

**OR**

5. Discuss the concept of the operating point (Q-point) of a BJT. Explain the significance of biasing in BJT circuits and describe different biasing methods, such as fixed bias, voltage-divider bias. [10M]

6. Explain the construction, operation, and characteristics of a N- channel Junction Field Effect Transistor (JFET). Discuss its V-I characteristics. [10M]

**OR**

7. Explain the basic digital operations of a system using logic gates. Discuss the working principles of OR, AND, NOT, XOR gates. Provide truth tables, logic symbols, and Boolean expressions for each gate. [10M]

8. Given the Boolean function  $F(A,B,C,D)$  represented by the minterms  $\sum m(1,3,7,11,15)$ , convert it to the Product of Sums (POS) form. Show all steps involved in the conversion, including the identification of maxterms and the construction of the POS expression. [10M]

**OR**

9. Explain the design and working of a binary adder. Compare the half-adder and full-adder circuits, including their logic diagrams, truth tables, and Boolean expressions. [10M]

10. Design a 4-bit serial-in, parallel-out shift register using D flip-flops. Provide the circuit diagram, truth table for flip-flops. [10M]

**OR**

11. Design a 3-bit synchronous up-counter using T flip-flops. Provide the state diagram, truth table for flip-flops, and the circuit diagram.. [10M]

\*\*\*\*\*